

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	"09544801"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:04
L2	10	"09/544801"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:12
L3	7443	((tft or (thin near film near transistor)) same (gate near5 electrode) same (gate near5 (wiring or metal or metallization or interconnect or interconnection or wire)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:14
L4	1484	(drive or driving or driven or driver) same ((tft or (thin near film near transistor)) same (gate near5 electrode) same (gate near5 (wiring or metal or metallization or interconnect or interconnection or wire)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:14
L5	939	(drive or driving or driven or driver) same pixel same ((tft or (thin near film near transistor)) same (gate near5 electrode) same (gate near5 (wiring or metal or metallization or interconnect or interconnection or wire)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:14
L6	276	(drive or driving or driven or driver) same pixel same ((tft or (thin near film near transistor)) same (gate near5 electrode) same (gate near5 (wiring or metal or metallization or interconnect or interconnection or wire))) same channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:17
L7	9504	257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:17

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L8	104	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls.) and (drive or driving or driven or driver) same pixel same ((tft or (thin near film near transistor)) same (gate near5 electrode) same (gate near5 (wiring or metal or metallization or interconnect or interconnection or wire))) same channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:19
L9	159	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls. or 257/E27.111.ccls. or 257/E29.275.ccls. or 257/E29.278.ccls.) and (drive or driving or driven or driver) same pixel same ((tft or (thin near film near transistor)) same (gate near5 electrode) same (gate near5 (wiring or metal or metallization or interconnect or interconnection or wire))) same channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:21
L10	14253	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls. or 257/E27.111.ccls. or 257/E29.275.ccls. or 257/E29.278.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:21
L11	99	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls. or 257/E27.111.ccls. or 257/E29.275.ccls. or 257/E29.278.ccls.) and (drive or driving or driven or driver) same pixel same ((tft or (thin near film near transistor)) same (gate near5 electrode) same (gate near5 (wiring or metal or metallization or interconnect or interconnection or wire))) same channel same region	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:23
L12	21	"5245207"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:22

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L13	208	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls. or 257/E27.111.ccls. or 257/E29.275.ccls. or 257/E29.278.ccls.) and (semiconductor same (gate near2 electrode) same (gate near2 (wire or wiring or interconnecte or metal or metallization)) same capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:24
L14	145	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls. or 257/E27.111.ccls. or 257/E29.275.ccls. or 257/E29.278.ccls.) and (semiconductor same (gate near2 electrode) same (gate near2 (wire or wiring or interconnecte or metal or metallization)) same ((storage or accumuation) near2 capacitor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:24
L15	143	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls. or 257/E27.111.ccls. or 257/E29.275.ccls. or 257/E29.278.ccls.) and (semiconductor same (gate near2 electrode) same (gate near2 (wire or wiring or interconnecte or metal or metallization)) same ((storage or accumuation) near2 capacitor) same (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:25
L16	12	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/350.ccls. or 257/351.ccls. or 257/344.ccls. or 257/E27.111.ccls. or 257/E29.275.ccls. or 257/E29.278.ccls.) and (semiconductor same (gate near2 electrode) same (gate near2 (wire or wiring or interconnecte or metal or metallization)) same ((storage or accumuation) near2 capacitor) same (film or layer)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:27
L17	37	("20010025960" "20010038097" "5594569" "5793460" "6067132" "6399988" "6429086" "6469317" "6531713" "6534826" "6569717" "6573564" "6579736" "6593592" "6753257" "6770936" "6777255" "6933571" "6936844" "7015141" "7049634").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/27 16:27